TTORNEY DOCKET NO.

PEARCE 26

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

plicant:

Charles W. Pearce

Serial No.:

09/755,826

Filed:

January 4, 2001

Title:

7/16/03 About 1 A METHOD OF MANUFACTURING A LATERALLY DIFFUSED

METAL OXIDE SEMICONDUCTOR DEVICE

Grp./A.U.:

2813

Examiner:

Chen, Jack S.

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

AMENDMENT UNDER 37 C.F.R. § 1.111

In response to the Examiner's Action mailed April 8, 2003, please amend the identified application as follows:

IN THE CLAIMS:

(Presently Amended) A method of manufacturing a laterally diffused metal oxide semiconductor (LDMOS) device, comprising: